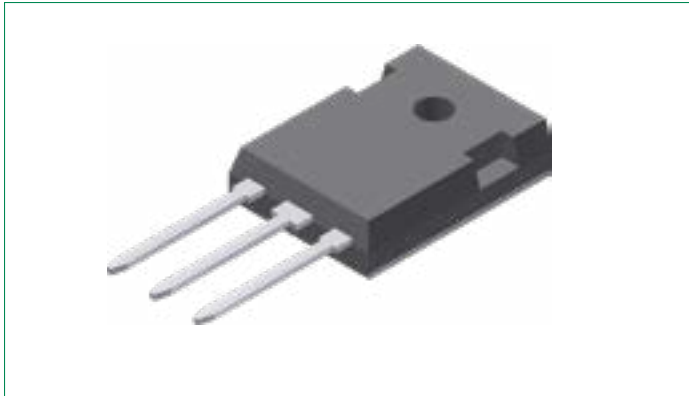


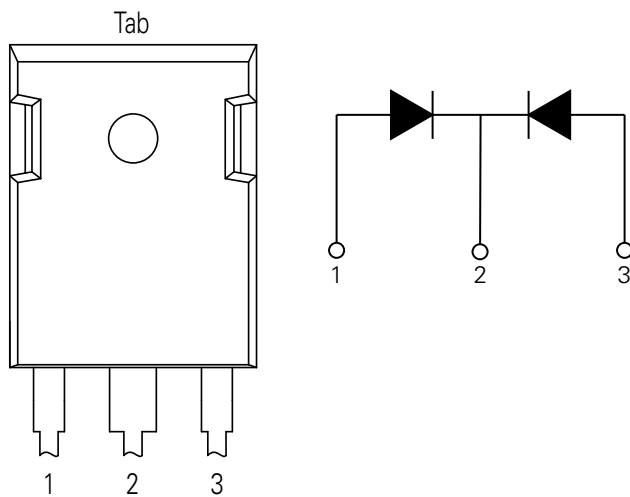
**DSSK50-01A**

100 V, 2 x 25 A Schottky Diode

RoHS

**Features:**

- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{RM}$  values
- Improved thermal behavior
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- RoHS compliant
- Epoxy meets UL 94 V-0

**Pinout Diagram (TO-247)**

**1:** Anode; **2:** Cathode ; **3:** Anode; **tab:** Cathode

**Applications:**

- Rectifiers in Switch Mode Power Supplies (SMPS)
- Free wheeling diode in low voltage converters

**Product Summary**

Characteristic	Value	Unit
$V_{RRM}$	100	V
$I_{FAV}$	2 x 25	A
$V_F$	0.61	V

## Maximum Ratings

Symbol	Characteristics	Condition	Max.	Units
$V_{RSM}$	Maximum Non-repetitive Reverse Blocking Voltage	$T_{VJ} = 25^{\circ}\text{C}$	100	V
$V_{RRM}$	Maximum Repetitive Reverse Blocking Voltage	$T_{VJ} = 25^{\circ}\text{C}$	100	V
$I_{RMS}$	RMS Current	per terminal	70	A
$I_{R(max)}$	Reverse Current	$V_R = 100\text{ V}, T_{VJM} = 25^{\circ}\text{C}$	1	mA
		$V_R = 100\text{ V}, T_{VJM} = 125^{\circ}\text{C}$	10	
$I_{FAV(max)}$	Average Forward Current Rectangular $d = 0.5$	$T_C = 164^{\circ}\text{C}, T_{VJM} = 175^{\circ}\text{C}$	25	A
$I_{FSM(max)}$	Maximum Forward Surge Current (Half Sine)	$t = 10\text{ ms}, (50\text{ Hz}), T_{VJM} = 45^{\circ}\text{C}$	650	A
$P_{tot(max)}$	Total Power Dissipation	$T_C = 25^{\circ}\text{C}$	215	W
$T_{VJ}$	Virtual Junction Temperature	–	-55 to +175	$^{\circ}\text{C}$
$T_{op}$	Operating Temperature	–	-55 to +150	$^{\circ}\text{C}$

## Electrical Characteristics

Symbol	Characteristics	Conditions	Specification	Units
$V_F$	Forward Voltage Drop	$I_F = 25\text{ A}; T_{VJM} = 25^{\circ}\text{C}$	0.76	V
		$I_F = 50\text{ A}; T_{VJM} = 25^{\circ}\text{C}$	0.85	
		$I_F = 25\text{ A}; T_{VJM} = 125^{\circ}\text{C}$	0.61	
		$I_F = 50\text{ A}; T_{VJM} = 125^{\circ}\text{C}$	0.70	
$V_{F0(max)}$	Threshold Voltage	$T_{VJM} = 175^{\circ}\text{C}$	0.47	V
$r_{F(max)}$	Slope Resistance		2.9	m $\Omega$
$C_{J(typ)}$	Junction Capacitance	$V_R = 5\text{ V}, T_{VJM} = 25^{\circ}\text{C}, f = 1\text{ MHz}$	1365	pF

## Thermal Specifications

Symbol	Characteristics	Condition	Specification	Units
$R_{thJC(max)}$	Thermal Resistance Junction to Case	–	0.7	K/W
$R_{thCH(typ)}$	Thermal Resistance Case to Heat Sink	–	0.3	K/W

Characteristic Curves

Figure 1. Maximum Forward Voltage Drop Characteristics

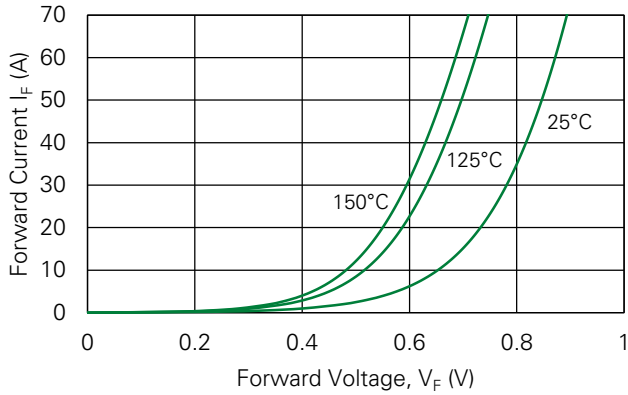


Figure 2. Typical Reverse Current vs. Reverse Voltage

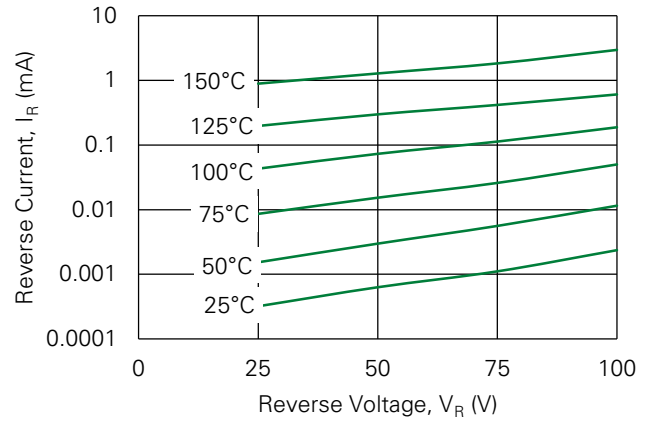


Figure 3. Typical Junction Capacitance vs. Reverse Voltage

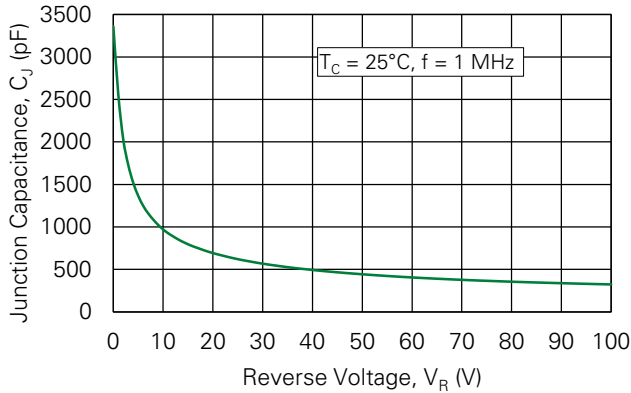


Figure 4. Average Forward Current vs. Case Temperature

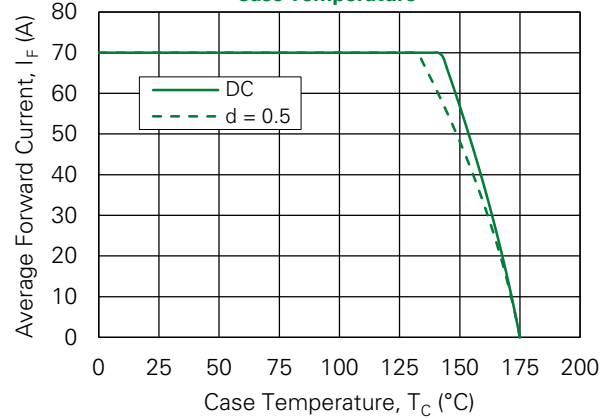


Figure 5. Forward Power Loss Characteristics

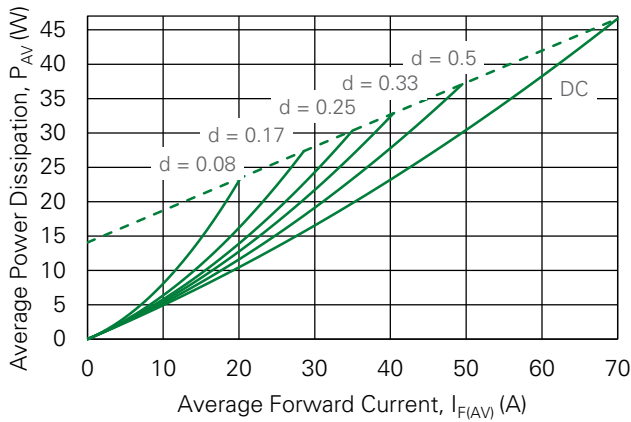
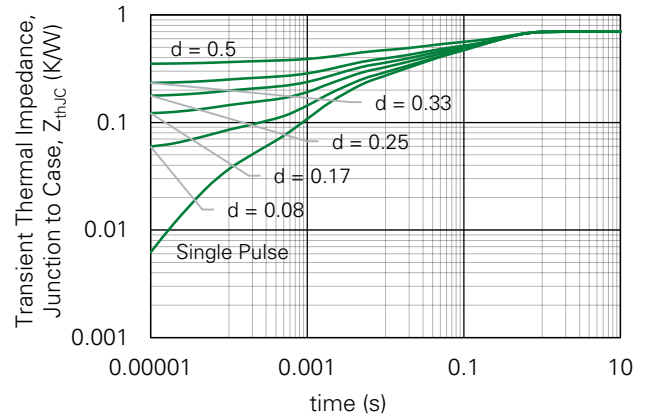
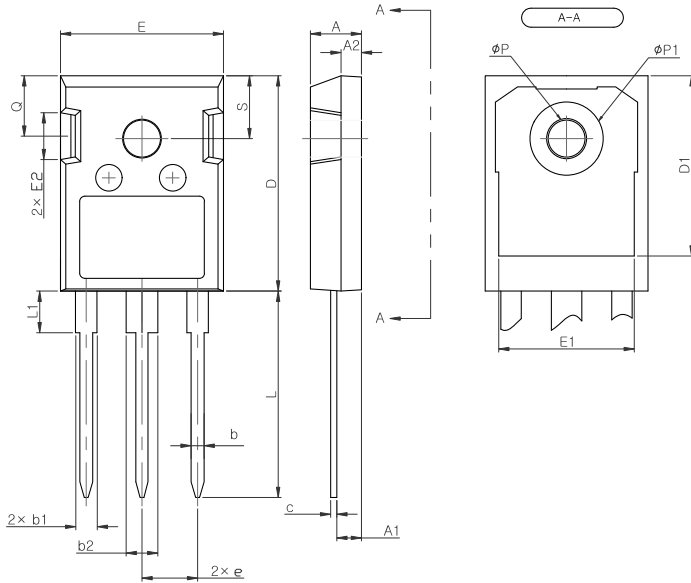


Figure 6. Transient Thermal Impedance

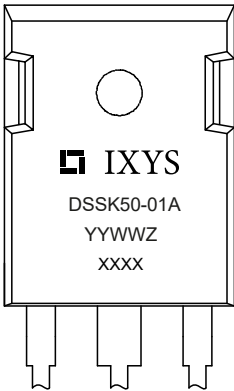


Part Outline Drawing (TO-247)



Symbol	Inches		Millimeters	
	Min.	Max.	Min.	Max.
A	0.189	0.205	4.80	5.20
A1	0.090	0.10	2.29	2.54
A2	0.075	0.083	1.90	2.10
b	0.043	0.051	1.10	1.30
b1	0.075	0.087	1.91	2.20
b2	0.115	0.126	2.92	3.20
c	0.020	0.027	0.50	0.70
D	0.819	0.840	20.80	21.34
D1	0.686	0.702	17.43	17.83
E	0.620	0.635	15.75	16.13
E1	0.514	0.530	13.06	13.46
E2	0.170	0.190	4.32	4.83
e	0.215 BSC		5.45 BSC	
L	0.781	0.797	19.85	20.25
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Ø P1	0.281-	0.285	7.14	7.24
Q	0.220	0.244	5.59	6.19
S	0.242 BSC		6.15 BSC	

Part Number and Marking



- D = Diode
- S = Schottky Diode
- SK = Product Generation
- 50 = Current Rate
- 01 = Voltage Rating
- A = Package Code
- YY = Year
- WW = Work Week
- Z = Plant Location Code
- xxxx = Lot Number

Ordering Information

Part Number	Marking	Packing Mode	Quantity
DSSK50-01A	DSSK50-01A	Tube	30 pcs/ tube

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